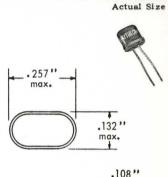


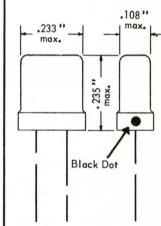
TECHNICAL INFORMATION

GOLD BONDED GERMANIUM DIODE

> TYPE 1N306

> > (CK 740)





Hence in Electron

The 1N306 is a hermetically sealed germanium Gold Bonded junction diode designed for general purpose applications and providing extreme stability, high forward current and high ratio of back to forward resistance. The flexible terminal leads may be soldered or welded directly to the terminals circuit components without the use of sockets. Standard inline subminiature sockets may be used by cutting the leads to a suitable length.

MECHANICAL DATA

CASE: Metal and Glass

BASE: None (0.016" tinned dumet wire. Length: 1.0" min. Spacing: 0.08" center-to-center)

TERMINAL CONNECTIONS: (Black Dot is adjacent to Cathode Terminal)

MOUNTING POSITION: Any

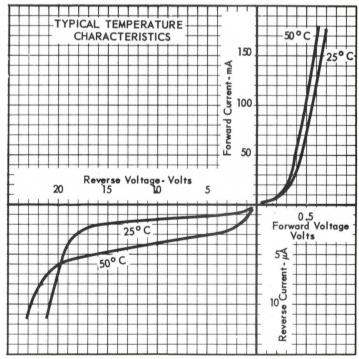
ELECTRICAL DATA

RATINGS - ABSOLUTE MAXIMUM VALUES: (at 25°C)

Peak Inverse Voltage Continuous Inverse Voltage Average Rectified Current Peak Rectified Current Surge Current (for 1 sec.) Ambient Temperature Range	300	volts volts ma. ma.
Dissipations at: 25°C 50°C	150 100	mw.

CHARACTERISTICS: (at 25°C)

Maximum Inverse Current at - 10 Volts Minimum Forward Current at + 0.8 Volts 2 μα. 100 ma.



Tentative Data

RAYTHEON MANUFACTURING COMPANY